

ROITHNER LASERTECHNIK GmbH

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v 6.0

SICO1S-C18

- UVC SiC photodiode according to DVGW W294
- PTB tested high chip stability
- Active Area: 0.06 mm²
- TO18 hermetically sealed metal housing
- 10mW/cm² → photocurrent of ~498nA





Description

SiC provides the unique property of extreme radiation hardness, near-perfect visible blindness, low dark current, high speed and low noise. These features make SiC the best available material for visible blind semiconductor UV detectors. The SiC detectors can be permanently operated at up to 170°C (338°F). The temperature coefficient of signal (responsivity) is also low, <-0.1%/K. Because of the low noise (dark current, in the fA range), very low UV radiation intensities can be measured reliably. Please note that this device needs an appropriate amplifier (see circuit on following page). SiC photodiodes are available as unfiltered broadband devices or with optical filters providing UV-A, UV-B, or UV-C-only sensitivity, or erythemal action curve compliance.

Maximum Ratings (T= 25°C)

Davameter	Cymhol	Val	l lmit	
Parameter	Symbol	Min.	Max.	Unit
Reverse Voltage	U _R	+20		V
Operating Temperature	T_{opr}	-55	+170	°C
Storage Temperature	T_{stg}	-55	+170	°C
Soldering Temperature (max. 3s)	T _{sol}		+260	°C

General Characteristics (T = 25°C)

Parameter	Symbol	Values			Unit
Farameter		Min.*	Тур.*	Max.*	Onit
Active Area	Α		0.06		mm²
Dark current (1V reverse bias)	I _d		0.2		fA
Capacitance	С		15		pF
Short circuit (10mW/cm² at peak)	I _D		498		nA
Temperature coefficient	T _C			-0.1	%/K

Spectral Characteristics (T = 25°C)

Davamatav	Cumbal	Values			Unit
Parameter	Symbol	Min.*	Тур.*	Max.*	Unit
Max. spectral responsivity	S _{max}	0.066		0.100	AW ⁻¹
Wavelength of max. spectral resp.	λ_{max}		268		nm
Responsivity range (S=0.1*S _{max})	-	221		284	nm
Visible blindness (S _{max} / S _{>405nm})	VB		10 ¹⁰		-

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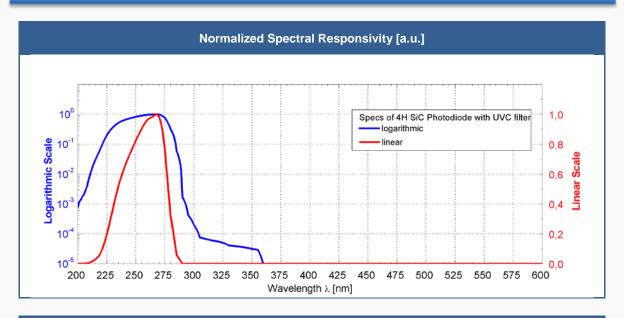


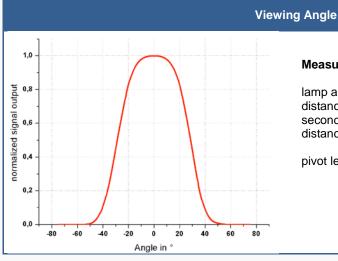
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Performance Characteristics





Measurement Setup

lamp aperture diameter: 10 mm distance lamp aperture to second aperture: 17 mm second aperture diameter: 10 mm

distance second aperture to detector: 93 mm

pivot level = top surface of the photodiode window

Product Portfolio

We offer the following selection of UV Photodiodes:

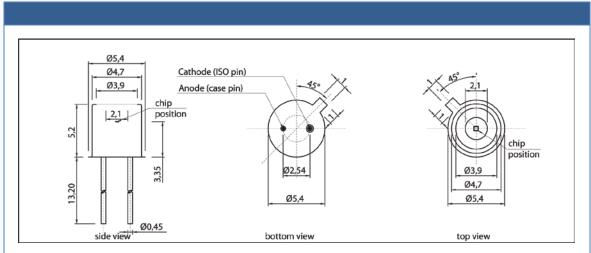
Option	UV sensitivity	Detector area	Max. spectral	responsivity
			min.	max.
SIC01S-18	UV broadband	0.06 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01S-C18	UVC	0.06 mm ²	0.066 AW ⁻¹	0.10 AW ⁻¹
SIC01S-C5	UVC	0.06 mm ²	0.066 AW ⁻¹	0.10 AW ⁻¹
SIC01S-18ISO90	UV broadband	0.06 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01M-18	UV broadband	0.2 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01M-5Lens	UV broadband	0.2 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01M-C5	UVC	0.2 mm ²	0.066 AW ⁻¹	0.10 AW ⁻¹
SIC01L-18	UV broadband	1.0 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01L-5	UV broadband	1.0 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹
SIC01L-C5	UVC	1.0 mm ²	0.066 AW ⁻¹	0.10 AW ⁻¹
SIC01XL-5	UV broadband	4.0 mm ²	0.085 AW ⁻¹	0.13 AW ⁻¹

Amplified photodiodes (TIAMO series) are also available.

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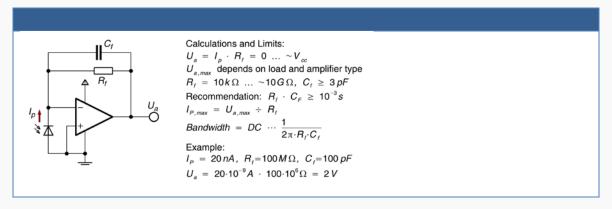


Outline Dimensions



All dimensions in mm

Circuit



Application Note

For correct reading of the photodiode the current (and NOT the voltage) must be analyzed. This requires a short circuiting of the photodiode. Usual approaches are using a Picoamperemeter or a transimpedance amplifier circuit as shown above.

To make the photodiode running reliably, particularly in harsh environment, EMC compatibility and protection against dust, water, and mechanical influences is required. Below listed modules base on a SiC photodiode and guarantee this protection and safety.

UVTIAMO: SiC photodiodes with **integrated amplifier** (0-5V output), available for power intensities ranging from 1.8 pW/cm² to 18 W/cm² for UV broadband, UVA, UVB, UVC or Erythema (UV-Index) measurements. **No additional amplifier needed, direct connection to voltmeter, controller, etc.**

UV-probe: SiC based sensor modules in **customizable industry grade housings** (e.g. cosine response, water pressure proof, sapphire windows) and **different electronic output configurations** (voltage, current, USB, Can) to choose from.

→ Ask us for further details!

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The above specifications are for reference purpose only and subjected to change without prior notice.

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